2SC5287

(Ta=25°C)

Silicon NPN Triple Diffused Planar Transistor (High Voltage Switching Transistor)

Application: Switching Regulator and General Purpose

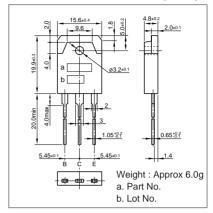
■Absolute maximum ratings (Ta=25°C)

Symbol	Ratings	Unit		
Vсво	900			
VCEO	550	V		
VEBO	7	V		
Ic	5(Pulse10)	А		
Ів	2.5	Α		
Pc	80(Tc=25°C)	W		
Tj	150	°C		
Tstg	-55 to +150	°C		

■Electrical Characteristics

Symbol	Conditions	Ratings	Unit
Ісво	Vcb=800V	100max	μΑ
І ЕВО	VEB=7V	100max	μΑ
V(BR)CEO	Ic=10mA	550min	V
hfe	Vce=4V, Ic=1.8A	10 to 25	
Vce(sat)	Ic=1.8A, IB=0.36A	0.5max	V
VBE(sat)	Ic=1.8A, IB=0.36A	1.2max	V
fr	Vce=12V, Ie=-0.35A	.35A 6typ	
Сов	VcB=10V, f=1MHz	50typ	рF

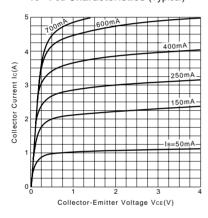
External Dimensions MT-100(TO3P)



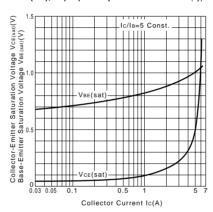
■Typical Switching Characteristics (Common Emitter)

Vcc (V)	RL (Ω)	Ic (A)	V _{BB1} (V)	VBB2 (V)	I _{B1} (A)	IB2 (A)	ton (µs)	tstg (µs)	tf (µs)
250	139	1.8	10	-5	0.27	-0.9	0.7max	4.0max	0.5max

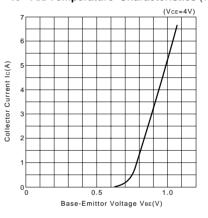
Ic-VcE Characteristics (Typical)



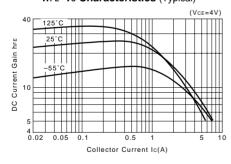
VcE(sat), VBE(sat)-Ic Temperature Characteristics (Typical)



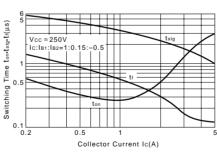
Ic-VBE Temperature Characteristics (Typical)



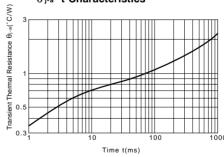
hfe-Ic Characteristics (Typical)



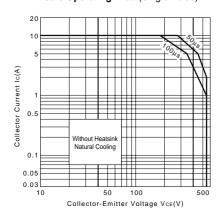
ton*tstg*tf-Ic Characteristics (Typical)



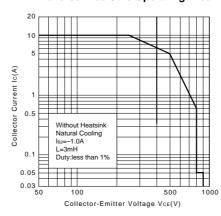
 $\theta_{\text{j-a}}\text{--t Characteristics}$



Safe Operating Area (Single Pulse)



Reverse Bias Safe Operating Area



Pc-Ta Derating

